

International
IR Rectifier

SD600N/R SERIES

STANDARD RECOVERY DIODES

Stud Version

Features

- Wide current range
- High voltage ratings up to 3200V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC types

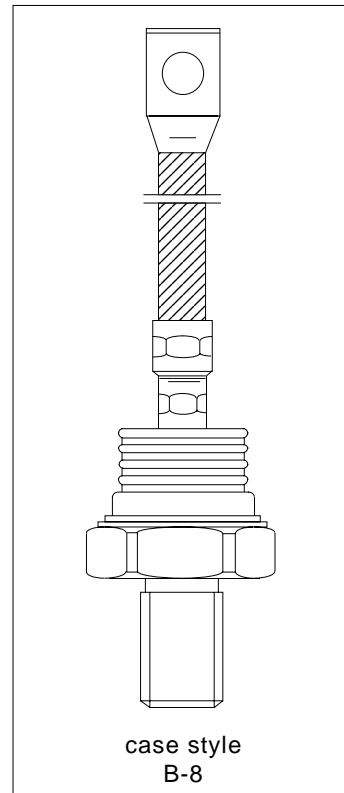
600A

Typical Applications

- Converters
- Power supplies
- Machine tool controls
- High power drives
- Medium traction applications

Major Ratings and Characteristics

Parameters	SD600N/R		Units	
	04 to 20	22 to 32		
$I_{F(AV)}$	600	600	A	
@ T_C	92	54	°C	
$I_{F(RMS)}$	940	940	A	
I_{FSM}	@ 50Hz	13000	10500	A
	@ 60Hz	13600	11000	A
I^2t	@ 50Hz	845	551	KA ² s
	@ 60Hz	772	503	KA ² s
V_{RRM} range	400 to 2000	2200 to 3200	V	
T_J	- 40 to 180	- 40 to 150	°C	



SD600N/R Series

Bulletin I2070 rev. C 03/03

International
IR Rectifier

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ $T_J = T_J$ max. mA
SD600N/R	04	400	500	35
	08	800	900	
	12	1200	1300	
	16	1600	1700	
	20	2000	2100	
	22	2200	2300	
	28	2800	2900	
	32	3200	3300	

Forward Conduction

Parameter	SD600N/R		Units	Conditions		
	04 to 20	22 to 32				
$I_{F(AV)}$ Max. average forward current @ Case temperature	600	600	A	180° conduction, half sine wave		
	92	54	°C			
$I_{F(AV)}$ Max. average forward current @ Case temperature	570	375	A	180° conduction, half sine wave		
	100	100	°C			
$I_{F(RMS)}$ Max. RMS forward current	940	940	A	DC @ $T_C = 75^\circ\text{C}$ (04 to 20), $T_C = 36^\circ\text{C}$ (25 to 32)		
I_{FSM} Max. peak, one-cycle forward, non-repetitive surge current	13000	10500	A	t = 10ms	No voltage	Sinusoidal half wave, Initial $T_J = T_J$ max.
	13600	11000		t = 8.3ms	reapplied	
	10900	8830		t = 10ms	100% V_{RRM}	
	11450	9250		t = 8.3ms	reapplied	
I^2t Maximum I^2t for fusing	845	551	KA ² s	t = 10ms	No voltage	
	772	503		t = 8.3ms	reapplied	
	598	390		t = 10ms	100% V_{RRM}	
	546	356		t = 8.3ms	reapplied	
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	8450	5510	KA ² √s	t = 0.1 to 10ms, no voltage reapplied		
$V_{F(TO)1}$ Low level value of threshold voltage	0.78	0.84	V	(16.7% $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), $T_J = T_J$ max.		
$V_{F(TO)2}$ High level value of threshold voltage	0.87	0.88		$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ max.		
r_{f1} Low level value of forward slope resistance	0.35	0.40	mΩ	(16.7% $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), $T_J = T_J$ max.		
r_{f2} High level value of forward slope resistance	0.31	0.38		$(I > \pi \times I_{F(AV)})$, $T_J = T_J$ max.		
V_{FM} Max. forward voltage drop	1.31	1.44	V	$I_{pk} = 1500\text{A}$, $T_J = T_J$ max, $t_p = 10\text{ms}$ sinusoidal wave		

Thermal and Mechanical Specifications

Parameter	SD600N/R		Units	Conditions
	04 to 20	22 to 32		
T _J Max. junction operating temperature range	-40 to 180	-40 to 150	°C	
T _{stg} Max. storage temperature range	-55 to 200	-55 to 200		
R _{thJC} Max. thermal resistance, junction to case	0.1		K/W	DC operation
R _{thCS} Max. thermal resistance, case to heatsink	0.04			Mounting surface, smooth, flat and greased
T Max. allowed mounting torque ±10%	50		Nm	Not lubricated threads
wt Approximate weight	454		g	
Case style	B-8			See Outline Table

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.012	0.008	K/W	T _J = T _J max.
120°	0.014	0.014		
90°	0.017	0.019		
60°	0.025	0.026		
30°	0.042	0.042		

Ordering Information Table

Device Code

SD	60	0	N	32	P	C
1	2	3	4	5	6	7

- 1** - Diode
- 2** - Essential part number
- 3** - 0 = Standard recovery
- 4** - N = Stud Normal Polarity (Cathode to Stud)
R = Stud Reverse Polarity (Anode to Stud)
- 5** - Voltage code: Code x 100 = V_{RRM} (See Voltage Ratings table)
- 6** - P = Stud base B-8 3/4" 16UNF-2A
- 7** - C = ceramic cap

NOTE: For Metric Device M24 x 1.5 Contact Factory

Outlines Table

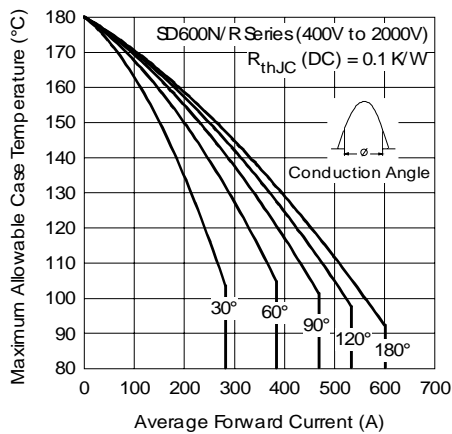
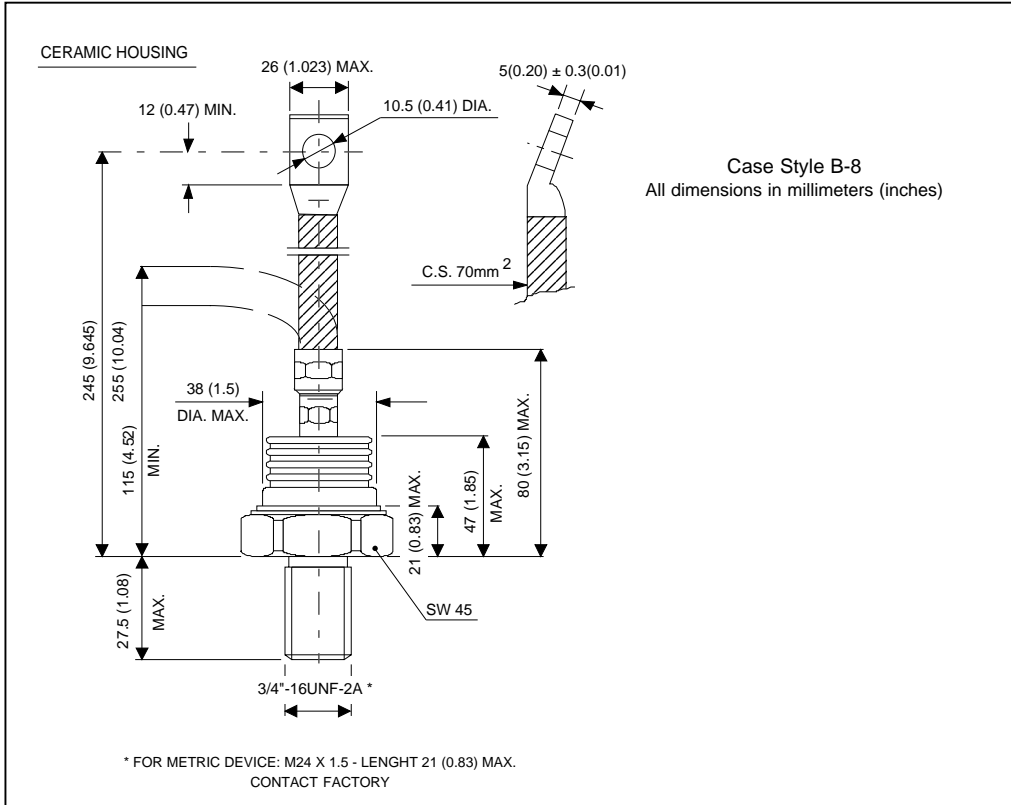


Fig. 1 - Current Ratings Characteristics

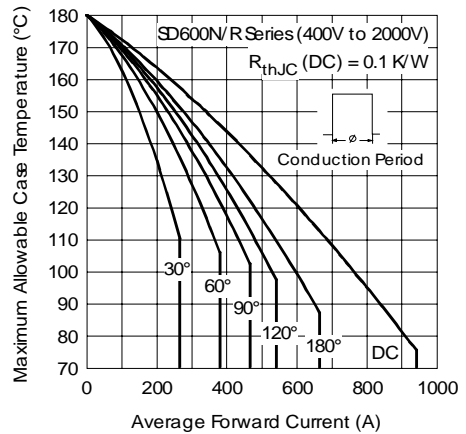


Fig. 2 - Current Ratings Characteristics

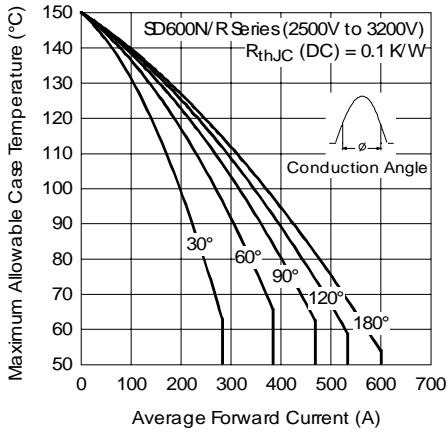


Fig. 3 - Current Ratings Characteristics

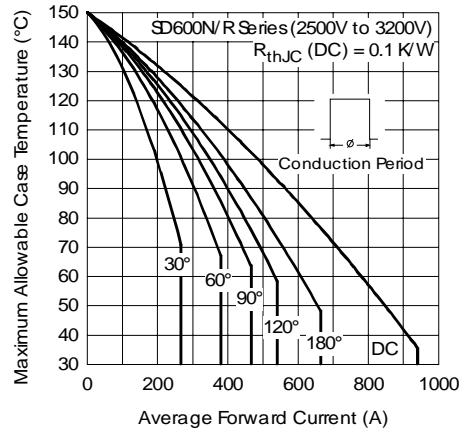


Fig. 4 - Current Ratings Characteristics

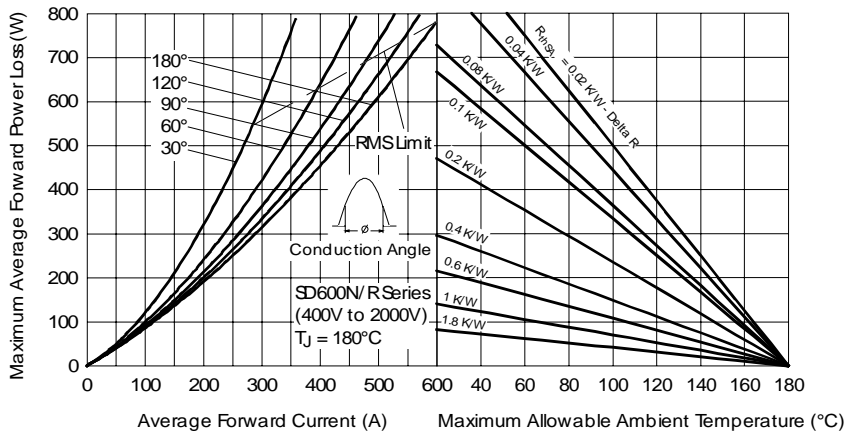


Fig. 5 - Forward Power Loss Characteristics

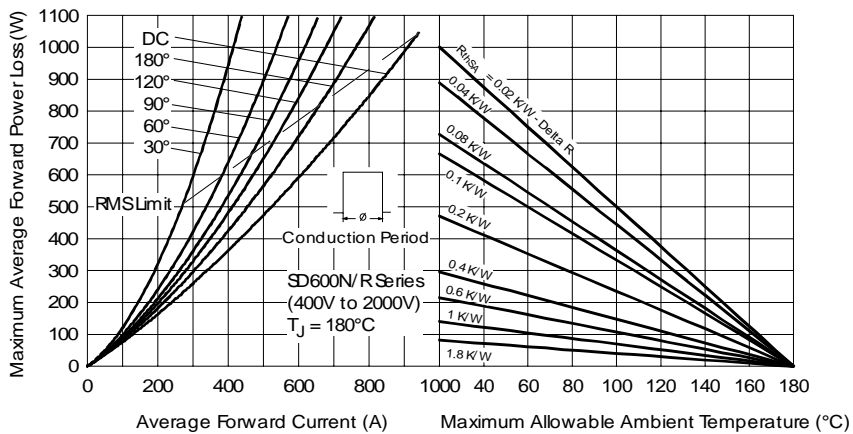


Fig. 6 - Forward Power Loss Characteristics

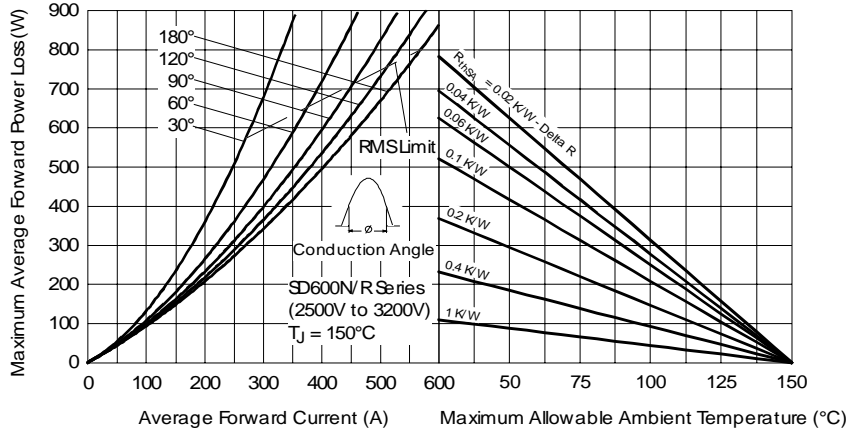


Fig. 7 - Forward Power Loss Characteristics

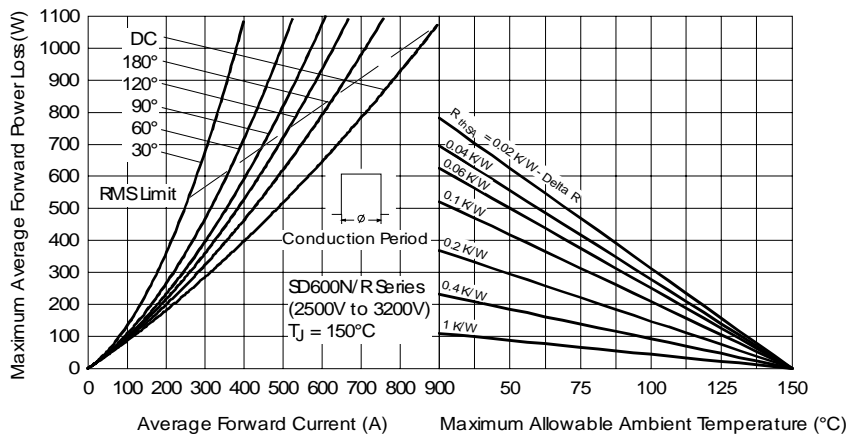


Fig. 8 - Forward Power Loss Characteristics

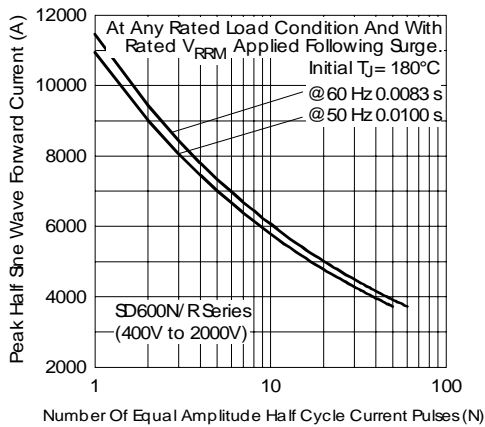


Fig. 9 - Maximum Non-Repetitive Surge Current

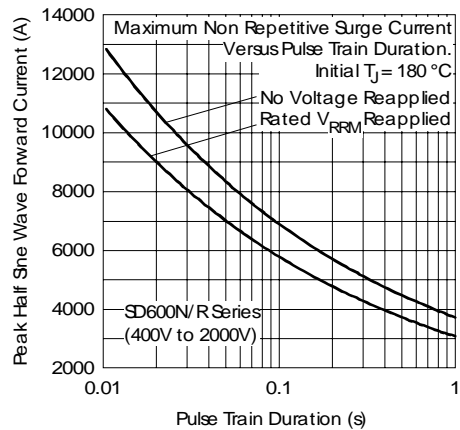


Fig. 10 - Maximum Non-Repetitive Surge Current

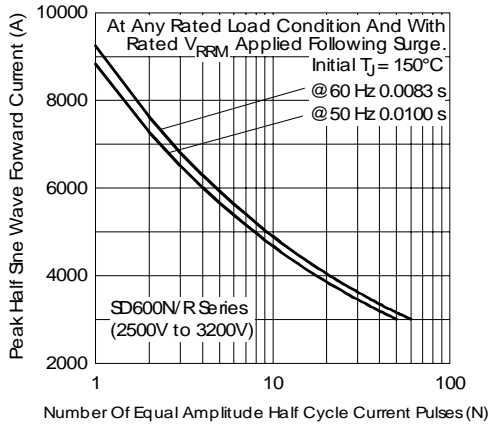


Fig. 11 - Maximum Non-Repetitive Surge Current

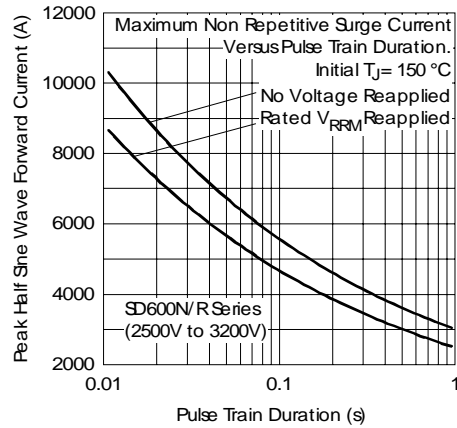


Fig. 12 - Maximum Non-Repetitive Surge Current

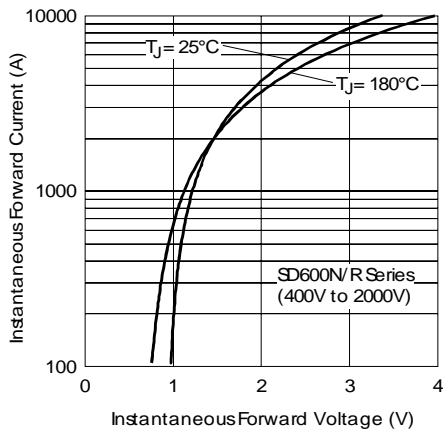


Fig. 13 - Forward Voltage Drop Characteristics

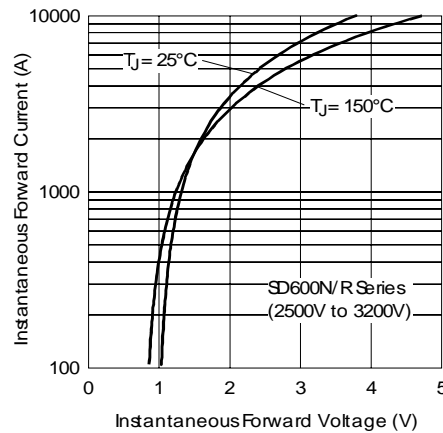


Fig. 14 - Forward Voltage Drop Characteristics

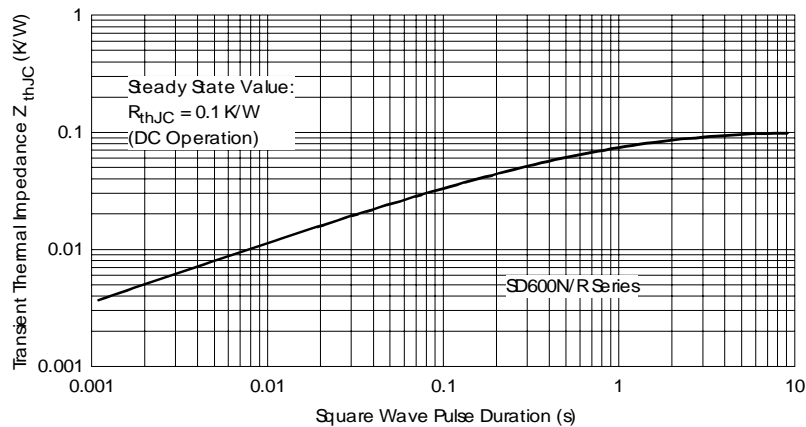


Fig. 15 - Thermal Impedance Z_{thJC} Characteristics

SD600N/R Series

Bulletin I2070 rev. C 03/03

International
IOR Rectifier

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
IOR Rectifier

IR WORLD HEADQUARTERS: 233 Kansas St., El Segundo, California 90245, USA Tel: (310) 252-7105
TAC Fax: (310) 252-7309
Visit us at www.irf.com for sales contact information. 03/03